



Stabilizing CsPbBr₃ perovskite quantum dots on zirconium phosphate nanosheets through an ion exchange/surface adsorption strategy

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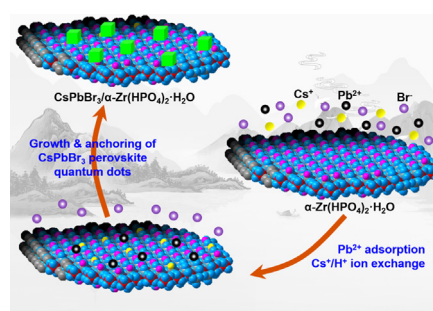
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HIGHLIGHTS

- An ion exchange/surface adsorption strategy was proposed to stabilize CsPbBr₃ PQDs.
- CsPbBr₃ PQDs were anchored on α -ZrP nanosheets.
- The CsPbBr₃ PQD/ α -ZrP composite exhibited greatly enhanced stability.

GRAPHICAL ABSTRACT



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ABSTRACT

All-inorganic perovskite quantum dots (PQDs) being characterized by high photoluminescence quantum yield, tunable emission colors and high color purity attract enormous attention in optoelectronic fields, especially as highly efficient narrow-band phosphors for lighting and next-generation display devices. However, poor stability seriously impedes their practical applications. Herein, we proposed an ion exchange/surface adsorption strategy to realize the room-temperature synthesis and stabilization of CsPbBr₃ PQDs on α -ZrP nanosheets. The inherent characteristics of the α -ZrP nanosheets including high Pb²⁺ adsorptivity and good Cs⁺ ion exchange capability promoted the heterogeneous nucleation-growth and effective anchoring of CsPbBr₃ PQDs on α -ZrP surfaces. Consequently, the synthesized α -ZrP/CsPbBr₃ composite exhibited superior green-emitting performance and significantly enhanced humidity stability and thermal stability in comparison to pure PQDs and many other matrix-protected PQDs. All these favorable characteristics listed above endowed the α -ZrP/CsPbBr₃ composite with good optical properties for lighting and displays. This work opens up a new way to use inorganic nanomaterials to stabilize all-inorganic PQDs and can promote the scalable synthesis of PQDs with long-term stability for optoelectronic devices.

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1. Introduction

All-inorganic CsPbX₃ (X = Cl, Br, I) perovskite quantum dots (PQDs) with regulatable halide components, high photoluminescence quantum yield (PLQY), tunable emission colors and high color purity attract enormous attention in optoelectronic fields, especially as highly efficient narrow-band phosphors for lighting and next-generation display devices [1–7]. However, their poor chemical stability, e.g., moisture sensitivity and thermal-induced degradation, hinders their practical applications for lighting and backlight displays [8–13]. For instance, when PQDs are utilized for light-emitting diodes (LEDs), lighting LEDs inevitably generate heat and cause the PQDs to be exposed to elevated temperatures. To stabilize CsPbX₃ PQDs, substantial efforts have been devoted, such as encapsulation using organic polymer matrices [14–16] or inorganic matrices [17–22]. Unfortunately, the protection offered by an organic polymer matrix is inadequate considering that many polymer matrices themselves cannot endure high temperatures. By contrast, inorganic matrices are generally stable at high temperatures, making it possible for them to improve the thermal stability of PQDs. Moreover, inorganic matrix-protected PQD composite powders have the advantage that they can be directly compatible with mature packaging techniques for commercial white LEDs [18,23]. To achieve better photoluminescence (PL) performance, surface design of inorganic matrices (e.g., designing aminated surface for silica particles) was performed to guarantee the uniform size and good dispersion of PQDs [18,19]. The essence is that these inorganic matrix materials with well-designed surfaces provide abundant sites for PQDs' nucleation-growth and adsorption [19]. However, it is undeniable that the surface design of inorganic matrix materials increases the complexity of the synthesis processes of PQDs.

In recent years, inorganic nanosheet materials are widely studied for electrochemical energy storage, catalytic reactions, optoelectronic devices, etc., benefiting from their unique micro-morphologies, relatively large specific surface area and subtle electronic structures [24–26]. This inspires us to explore the feasibility of utilizing inorganic nanosheets as a matrix to protect PQDs. Considering that appropriate interaction between matrix surface and PQDs is helpful to anchor PQDs and prevent PQDs' aggregation at high temperatures or in moist environments, seeking suitable inorganic nanosheet materials that can interact positively with PQDs and thus stabilize PQDs is highly desired, whereas the interfacial engineering of inorganic nanosheet-PQDs is a big challenge. Zirconium phosphate nanosheets, with the chemical formula of α -Zr(HPO₄)₂·H₂O (α -ZrP), own unique ion exchange/surface adsorption properties, typical layered structure and good heat stability, thus have been applied for sewage treatment, etc [27–29]. However, to our best knowledge, α -ZrP nanosheets have never been used to stabilize CsPbBr₃ PQDs.

Herein, we proposed an ion exchange/surface adsorption strategy to realize the room-temperature synthesis and stabilization of CsPbBr₃ PQDs on α -ZrP nanosheets (Fig. 1). This strategy was achieved based on the high Pb²⁺ adsorptivity and good Cs⁺ ion exchange capability of α -

ZrP nanosheets, which promoted the heterogeneous nucleation-growth and effective anchoring of CsPbBr₃ PQDs on the α -ZrP surfaces. The synthesized α -ZrP/CsPbBr₃ composite exhibited superior green-emitting behavior and significantly enhanced humidity and thermal stability, which endowed them with attractive performance in white LEDs and displays. This work provides an effective strategy using inorganic nanomaterial matrices for facile synthesis and stabilization of all-inorganic PQDs for optoelectronic devices.

2. Experimental

2.1. Chemicals and materials

All chemicals were used as received without further purification. Oleic acid (OA) and oleylamine (OAm) were purchased from Aladdin Reagent Co., Ltd. N, N-Dimethylformamide (DMF) and toluene were supplied by Sinopharm Chemical Reagent Co., Ltd. PbBr₂ (99.99%) and CsBr (99.9%) were obtained from Xi'an Polymer Light Technology Corp. α -ZrP was provided by Sunshine Technology Co., Ltd. The blue LED chip was obtained from EPI LEDs Co., Ltd. Commercial phosphors of (Sr,Ca)AlSiN₃:Eu²⁺, K₂SiF₆:Mn⁴⁺ (i.e., KSF) and (Sr,Ba)₂SiO₄:Eu²⁺ were purchased from Shenzhen Looking Long Technology Co., Ltd.

2.2. Synthesis of α -ZrP/CsPbBr₃ composite powder

0.4 mmol of PbBr₂ and 0.4 mmol of CsBr were dissolved in DMF (10 mL) while stirring, then 1 mL of OA and 0.5 mL of OAm were added as ligands to form a precursor solution. Separately, 0.2 g α -ZrP powder was dispersed in 10 mL of toluene under stirring. Subsequently, 1 mL of the above precursor solution was added to the α -ZrP/toluene system under stirring for 1 min at room temperature and then left to stand for 30 min. The produced powder was collected at the bottom of the beaker, washed with hexane and naturally dried in the air to get an α -ZrP/CsPbBr₃ PQD composite.

2.3. Assembly of α -ZrP/CsPbBr₃ LEDs

Two kinds of white LEDs were assembled with the synthesized α -ZrP/CsPbBr₃ composite powder, a blue InGaN chip and a commercial red phosphor of (Sr,Ca)AlSiN₃:Eu²⁺ or KSF. In detail, the red phosphors and the α -ZrP/CsPbBr₃ composite powder were mixed with silicone thoroughly to form a hybrid sol and then dropped onto the blue-emitting InGaN chip. Also, a green LED was constructed by spreading the α -ZrP/CsPbBr₃ composite powder on a blue InGaN chip.

2.4. Characterization

X-ray diffraction (XRD) analyzer (model: Ultima-IV) with a Cu K α radiation was used to analyze the crystal structure of samples. Valence states of elements in the α -ZrP/CsPbBr₃ composite were detected by X-ray photoelectron spectroscopy (XPS; model: PHI Quantum-2000). The

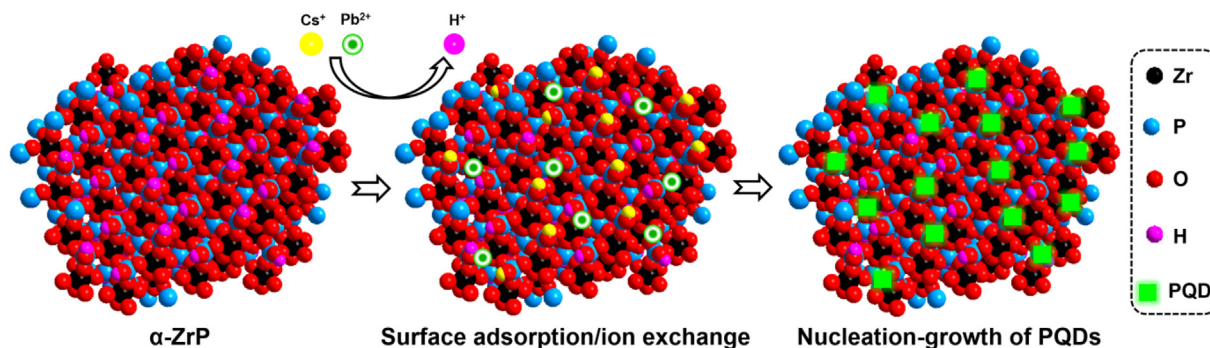


Fig. 1. Schematic illustration for the synthesis of CsPbBr₃ PQDs on α -ZrP nanosheets.

microscopic-morphologies of the samples were observed using field emission scanning electron microscopy (SEM; model: SUPRA 55) and high-resolution transmission electron microscopy (TEM; model: FEI Tecnai G2 F30). Fourier transform infrared spectroscopy (FTIR) analysis was carried out using a spectrometer (model: Nicolet iS5). Thermogravimetric (TG) measurements and N₂ adsorption/desorption tests were performed on a simultaneous thermal analyzer (model: Netzsch STA 449 F5 Jupiter) and a Brunauer-Emmett-Teller (BET) analyzer (model: ASAP 2020M + C), respectively. PL emission spectra and PLQY tests were carried out on a fluorescence spectrophotometer equipped with visible and near-infrared photomultiplier tube detectors (model: FLS980, Edinburgh Instruments). The humidity stability of the α -ZrP/CsPbBr₃ composite was examined by keeping it in a moist environment (room temperature with ~80% humidity) and its PL emission spectra were recorded every few hours. A charge-coupled device (model: Ocean Optics, USB2000+) and a cooling/heating stage (model: Linkam Scientific Instruments, THMS600E) were used to record temperature-dependent PL spectra (temperature range: 0–100 °C). The electroluminescence (EL) spectra, luminous efficacy, correlated color temperature (CCT), color-rendering index (CRI), Commission International De L'Eclairage (CIE) and color purity of these LEDs were analyzed using an integrating sphere (HAAS-2000, Everfine, China).

3. Results and discussion

As-received α -ZrP is a white powder with a nanosheet-like micro-morphology and lateral dimension of 1–4 μm (Fig. 2a). Most of the α -ZrP sheets possess a thickness of less than 100 nm as shown in Fig. S1. N₂ adsorption-desorption isotherms in Fig. S2 show that the α -ZrP sample is a typical mesoporous material. Besides, the α -ZrP raw-material has high crystallinity, reflected by the sharp diffraction peaks at 11.7°, 19.8°, 24.9°, 33.8° and so on in the XRD pattern (Fig. 2b), correspond well to the α -ZrP phase (PDF#34-0127). More importantly, α -ZrP possesses a layered crystal structure and massive hydroxyl (–OH)

groups on the surface (as illustrated in Fig. 2c), and has been widely used for waste water treatment and catalytic reactions, benefiting from its good ion exchange ability and high Pb²⁺ adsorptivity [30–33]. Especially, surface ion exchange between monovalent Cs⁺ and H⁺ on the α -ZrP surface is easy to happen [31], although large radius makes Cs⁺ cations hard to directly intercalate into α -ZrP (note that ion exchange between Pb²⁺ and α -ZrP through an intercalation process is also possible, but corresponding kinetics is relatively slow) [32]. The acidity of the hydrogen atoms that are bound to anionic HPO₄²⁻ groups is very low, and they are readily exchanged for other cations such as Cs⁺ [32,34]. This can be considered as the driving force for surface ion exchange between Cs⁺ and H⁺ on the α -ZrP surface. In order to verify the surface ion exchange behavior between monovalent Cs⁺ and H⁺ on the α -ZrP surface, we immersed α -ZrP powder in CsBr/DMF solution for 1–2 min and then washed for several times. SEM image, EDS mapping and XPS spectra of the treated powder are given in Fig. 2d and Fig. S3. The detected Cs element confirms the surface ion exchange between Cs⁺ and H⁺ on the α -ZrP surface. Remarkably, the surface ion exchange behavior between Cs⁺ and H⁺ will be very useful for anchoring CsPbBr₃ PQDs on the surface of α -ZrP nanosheets during the synthesis process of the α -ZrP/CsPbBr₃ PQD composite.

For the synthesized α -ZrP/CsPbBr₃ PQD composite, it has a similar micro-morphology compared to the pristine α -ZrP nanosheets (Fig. 3a and Fig. S1), while EDS mapping result in Fig. 3b reveals a uniform distribution of PQDs in the composite. Also, the PQDs are directly observed on the surface of the α -ZrP nanosheets from the high-resolution TEM image in Fig. 3c: the PQDs have a size of about 4–7 nm and the fringe spacing is measured to be 0.24 nm consistent to the index of (2 1 1) crystal plane of cubic CsPbBr₃ PQDs. The XRD pattern of the α -ZrP/CsPbBr₃ PQD composite powder is displayed in Fig. 3d. Due to the very small size of the CsPbBr₃ PQDs (as discussed in Fig. 3c), and being enveloped by the α -ZrP nanosheets, characteristic diffraction peaks of CsPbBr₃ PQDs are relatively weak [35,36]. Despite this, the diffraction peaks at $2\theta = 30.6^\circ$, etc., can be indexed to cubic CsPbBr₃ PQDs

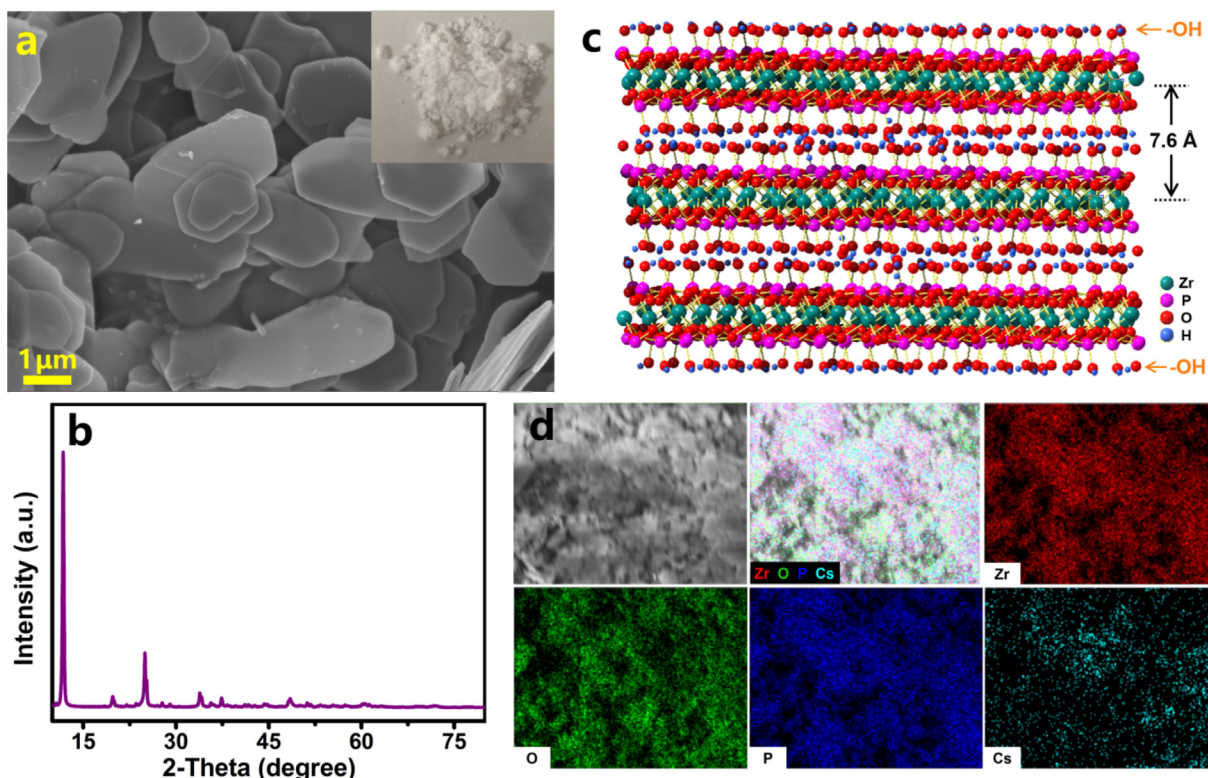


Fig. 2. (a) SEM image (inset: photograph) and (b) XRD pattern of the as-received α -ZrP powder. (c) Schematic illustration of α -ZrP crystal structure. (d) EDS mapping of the α -ZrP powder after surface ion exchange with Cs⁺.

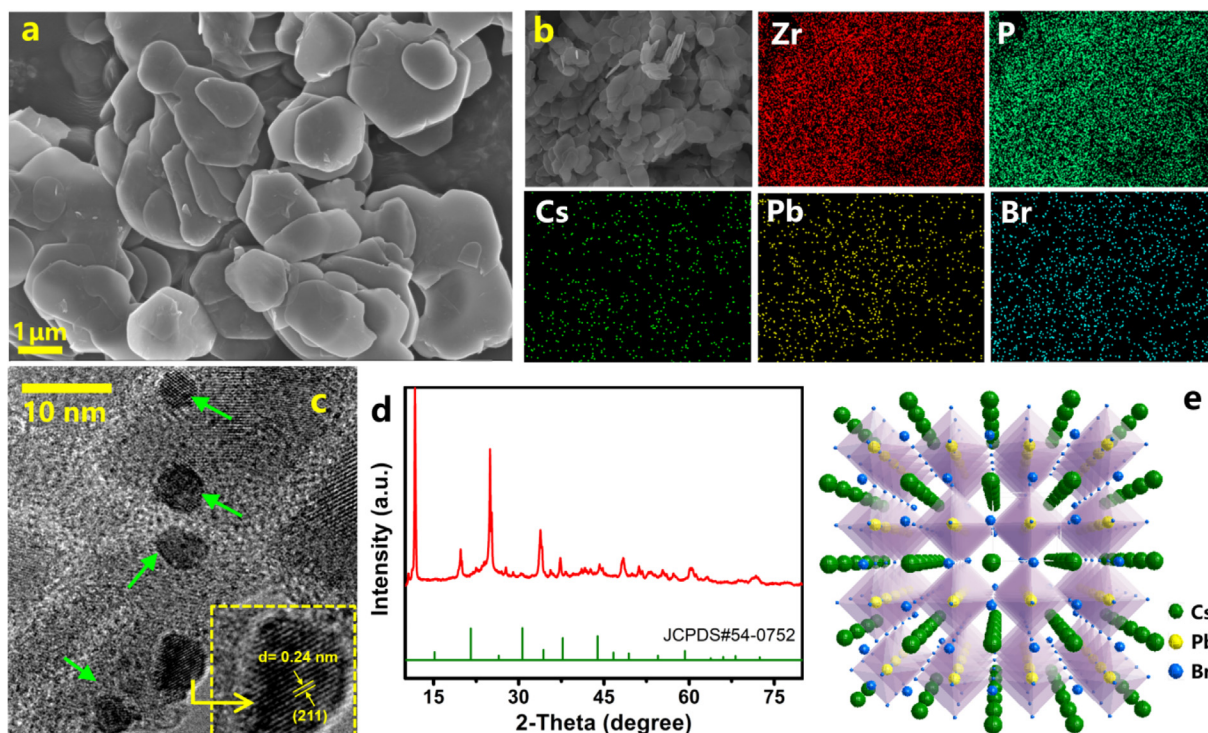


Fig. 3. (a) SEM image, (b) EDS mapping (with the analysis area of $\sim 400 \mu\text{m}^2$), (c) high-resolution TEM images (the particles pointed out by green arrows are CsPbBr₃ PQDs and inset shows the particles' lattice fringes) and (d) XRD pattern of the α -ZrP/CsPbBr₃ PQD composite powder. (e) Crystal structure of cubic CsPbBr₃ PQDs. (For interpretation of the references to color in this figure legend, the reader is referred to the web version of this article.)

(PDF#54-0752; as illustrated in Fig. 3e).

To comprehensively investigate the α -ZrP/CsPbBr₃ PQD composite, XPS, FTIR spectroscopy and TG analysis were performed. In the XPS full spectrum of the α -ZrP/CsPbBr₃ PQD composite powder (Fig. 4a), the signals related to Zr, P, O, Cs, Pb, and Br elements are detected. In detail, XPS fine spectra in Fig. 4b–d suggest that binding energies of Cs

3d_{5/2} (723.8 eV), Cs 3d_{3/2} (737.9 eV), Pb 4f_{7/2} (138.4 eV), Pb 4f_{5/2} (143.2 eV), Br 3d_{5/2} (68.2 eV) and Br 3d_{3/2} (69.3 eV) are close to the values for CsPbBr₃ PQDs that have been reported in the literature, further confirming the formation of CsPbBr₃ PQDs in the α -ZrP/CsPbBr₃ PQD composite powder [14,22,37]. Note that anchoring of PQDs on the α -ZrP nanosheets inevitably affects the binding energies of

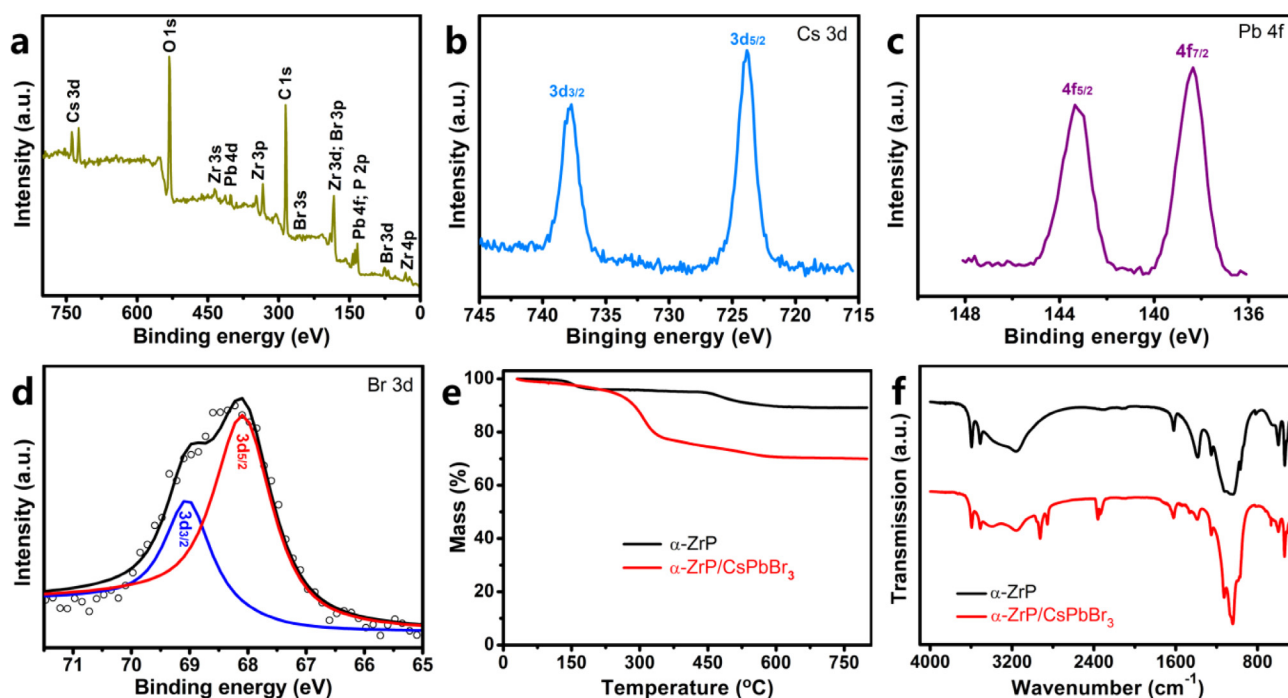


Fig. 4. (a–d) XPS spectra, (e) TG curve and (f) FTIR spectrum of the α -ZrP/CsPbBr₃ composite powder. (a), (b), (c) and (d) are XPS full spectrum, Cs 3d spectrum, Pb 4f spectrum and Br 3d spectrum, respectively. TG curve and FTIR spectrum of α -ZrP are provided in (e) and (f), respectively.

Cs 3d, Pb 4f, and Br 3d to some extent. Apart from PQDs and α -ZrP, possibly preserved organic components (e.g., DMF, OA and OAm) in the synthesized composite powder were studied. From the TG curve of the pure α -ZrP in Fig. 4e, we can see that α -ZrP is stable before 120 °C and then two weight loss sections appear. The weight loss in the temperature range of 120–210 °C and 430–650 °C is associated with the removal of H₂O from the monohydrate α -ZrP and the process that phosphate groups condense to zirconium pyrophosphate [38], respectively. For the α -ZrP/CsPbBr₃ composite sample, it shows an additional mass loss in the temperature of 210–430 °C. This proves the existence of OA and OAm in the composite because boiling points of the two ligands are in such a temperature range. As shown in Fig. 4f, the FTIR spectrum of the α -ZrP contains an intense characteristic peak at 1050 cm⁻¹, originating from the P-O stretching vibration of interlayer PO₄ groups. The broad adsorption bands at 3590, 3510, 3150 and 1618 cm⁻¹ can be ascribed to the OH stretching vibration of α -ZrP [39–41]. For the α -ZrP/CsPbBr₃ composite, some other adsorption bands are observed. The adsorption band at 3305 cm⁻¹ is an NH stretching mode, indicating the presence of OAm [42]. Typical absorption band for the species with hydrocarbon groups is detected at 2935 cm⁻¹, and two asymmetric vibrations with one symmetric stretching vibration of the carboxylate group are also found at 1520 and 1410 cm⁻¹. These bands are considered to be from OA [43,44]. In short, TG and FTIR results prove the presence of OA and OAm in the α -ZrP/CsPbBr₃ PQD composite. It is considered that the two hydrophobic ligands (i.e., OA and OAm) can help to control PQDs' size, prevent PQD aggregation and enhance PQDs' stability [9,45].

The above discussions clearly demonstrate the presence of CsPbBr₃ PQDs on the α -ZrP nanosheets. It is equally necessary to probe into the formation process of the PQDs and their interaction with the α -ZrP nanosheets. As mentioned above, α -ZrP possesses a good ion exchange ability and high Pb²⁺ adsorptivity [30–33]. Therefore, during the synthesis of the α -ZrP/CsPbBr₃ composite, when CsBr-PbBr₂-DMF precursor was mixed with the α -ZrP/toluene suspension, Cs⁺ and Pb²⁺ would be adsorbed onto the surface of the α -ZrP nanosheets, accompanied by a surface ion exchange between some Cs⁺ and the α -ZrP (Fig. 2d and Fig. S3), and then CsPbBr₃ PQDs nucleated and grew up around these Pb²⁺ and Cs⁺ that located on the α -ZrP surfaces (as illustrated in Fig. 1. Note that some PQDs would spontaneously form in the solution, instead of on α -ZrP nanosheet surfaces, while these PQDs were removed during the washing process with hexane). Obviously, such a formation process benefits to the strong anchoring of the PQDs on the α -ZrP nanosheets. Evidence of this strong anchoring is that the PQDs were not observed to fall off from the α -ZrP even the synthesized α -ZrP/CsPbBr₃ composite powder was mixed with hexane and then shook vigorously (Fig. S4).

Luminescence properties of the synthesized α -ZrP/CsPbBr₃ composite are then investigated. The α -ZrP/CsPbBr₃ sample is a yellow powder, which exhibits intense green emission under irradiation from a UV (365 nm) light (inset in Fig. 5a). In its PL spectrum under an excitation wavelength of 450 nm, a highly symmetric emission peak centered at ~517 nm and a narrow full width at half maximum (FWHM) of 23 nm under an excitation wavelength of 450 nm are observed (Fig. 5a), indicating good green-emitting performance of the composite. The FWHM of the α -ZrP/CsPbBr₃ composite is much narrower than that of commercial phosphors (Fig. S5), which is essential to obtain high color purity for display applications. Meanwhile, a PLQY of 50% is achieved (Fig. S6). This value is notably higher than the figures for previously reported pure CsPbBr₃ PQDs (with a low PLQY of 6%), ethyl cellulose/CsPbBr₃ PQD composite films (PLQY of 37%) and glass protected CsPbBr₃ PQDs (PLQY of 42%) [15,21,46]. This high PLQY is comparable to that of natural mineral halloysite nanotube/PQDs, aminated SiO₂ particles/PQDs and mesoporous metal-organic frameworks/PQDs that were synthesized at high temperatures [19,21,35]. For pure PQDs in the solid state, ligands are easy to detach from their surface. As a result, surface defects form and PQD particles aggregate in air, leading to a low PLQY [47]. While for the ethyl cellulose/CsPbBr₃

PQD composite film [15], the PQDs were synthesized firstly and then hybridized with ethyl cellulose. Obviously, the PQDs were not under protection before hybridizing with the ethyl cellulose film. Meanwhile, during the polymerization of the composite film, the PQDs may aggregate and grow into large nanocrystals. By contrast, for the α -ZrP/CsPbBr₃ PQDs composite, natural mineral halloysite nanotube/PQDs, aminated SiO₂ particles/PQDs and mesoporous metal-organic frameworks/PQDs [19,21,35], PQDs were *in-situ* grew on the surfaces of these inorganic materials and exhibited a small size. Besides, these inorganic matrices could also passivate the PQDs [20,48,49]. Consequently, these composites were endowed with higher PLQY values. In addition, a green LED constructed using the α -ZrP/CsPbBr₃ composite powder and a blue InGaN chip also confirms the composite's outstanding green-emitting performance with CIE chromaticity coordinate of (0.164, 0.772) and high color purity of 92% (Fig. 5b and Fig. S7).

The lead halide perovskite nanocrystal structure of CsPbBr₃ PQDs with ionic nature tends to degrade when CsPbBr₃ PQDs contact a moist environment [50,51]. They are also easy to aggregate when the PQDs are exposed to relatively high temperatures (it is considered that thermal-induced PL quenching mainly arises from the degradation and agglomeration of PQDs [20,22]). That is, PQDs possess poor humidity stability and thermal stability, inevitably leading to modest performance of PQDs-based optoelectronic devices. Therefore, how to enhance humidity stability and thermal stability of CsPbBr₃ PQDs is a critical issue for their practical applications. It is inspiring to find that our α -ZrP/CsPbBr₃ composite shows excellent humidity stability: its PL intensity declines only ~16% of its initial intensity after exposure to the humid environment for ~640 h (Fig. 6a). Such humidity stability is much better than that of pure CsPbBr₃ PQDs and some other inorganic matrices (e.g., CaF₂ and *h*-BN nanosheets) protected CsPbBr₃ PQDs [20,22], showing the prominent advantage of using α -ZrP nanosheets to stabilize PQDs. As pointed by Huang et al. [52], moisture-induced degradation of PQDs is always accompanied by the increased size of PQD nanocrystals. In our α -ZrP/CsPbBr₃ composite, the CsPbBr₃ PQDs are anchored on the surface of the α -ZrP nanosheets. Meanwhile, the “wall-like” α -ZrP nanosheets separate the PQDs (as illustrated in Fig. S8). Therefore, PQDs' movement and regrowth into large crystals are suppressed. This mechanism has also been confirmed in other inorganic materials protected PQDs [19,22]. At the same time, the remaining OA and OAm ligands in the composite serve as a water-resisting layer and contribute to the enhancement of the PQDs' humidity stability [9,45]. Besides, even after 7 months since the synthesis of the α -ZrP/CsPbBr₃ composite (note that the composite was stored in air with a humidity of 30–60% during the 7 months), the composite powder exhibits intense green emission under UV light (inset in Fig. 6a), and its PLQY retention is about 50%. Serious aggregation of PQDs is not observed in the TEM and high-resolution TEM images of the α -ZrP/CsPbBr₃ composite after 7-month storage (Fig. S9). These suggest that the α -ZrP/CsPbBr₃ composite has a relatively good long-term storage stability.

Moreover, the thermal stability of the PQDs is also improved by hybridizing with the α -ZrP nanosheets. We can intuitively see from Fig. 6b and Fig. S10 that during a heating-cooling process (i.e. the temperature was raised from 0 to 100 °C and then cooled down to 0 °C), the PL intensity of the α -ZrP/CsPbBr₃ composite decreases with increasing temperature and then increases with decreasing temperature, and finally, the PL intensity recovers up to 94% of its initial value (Fig. 6c). By contrast, the PL intensity of pure CsPbBr₃ PQDs only retained 35% of its original intensity when the temperature increased from room temperature to 100 °C and then decreased to the room temperature (inset in Fig. 6c) [48]. Furthermore, during repeated heating-cooling processes, the α -ZrP/CsPbBr₃ composite also exhibits high PL recovery ability (Fig. S11). The excellent thermal stability of the α -ZrP/CsPbBr₃ composite can be attributed to several reasons: (i) outstanding thermal stability of α -ZrP itself is essential to protect CsPbBr₃ PQDs under high temperature [53,54]; (ii) the PQDs are anchored on the α -ZrP nanosheets and the “wall-like” α -ZrP nanosheets

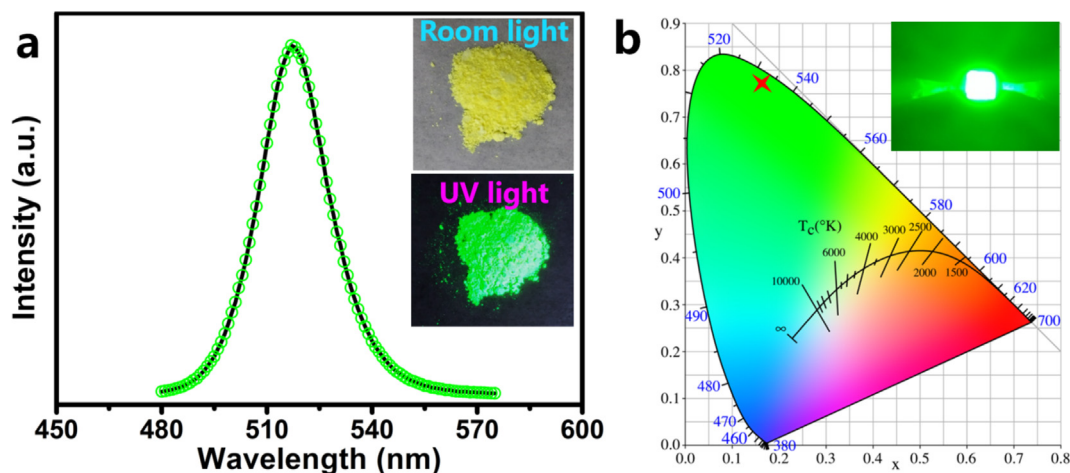


Fig. 5. (a) PL emission spectrum and photographs (insets) of the α -ZrP/CsPbBr₃ composite powder. (b) CIE chromaticity diagram of the green-emitting LED constructed by the α -ZrP/CsPbBr₃ PQD composite and a blue InGaN chip (inset: photograph of the lighting green-emitting LED). (For interpretation of the references to color in this figure legend, the reader is referred to the web version of this article.)

separate the PQDs from each other (Fig. S8), making the PQDs hard to regrow into large crystals when the α -ZrP/CsPbBr₃ composite is exposed to high temperatures (as confirmed by TEM observations of the α -ZrP/CsPbBr₃ composite before and after heat treatment in Fig. S9) [20,48,55]; (iii) high temperatures would accelerate moisture-induced decomposition of PQDs [56], while our α -ZrP/CsPbBr₃ composite possesses a superior humidity stability, thus the negative effects of high temperature will be alleviated. Additionally, the α -ZrP/CsPbBr₃ composite also exhibits a relatively good photo-stability, with 88% PL intensity retention after 36 h light irradiation (Fig. S12).

The optical properties of the α -ZrP/CsPbBr₃ composite for white LEDs and display applications are further studied. A white LED was constructed with the green-emitting α -ZrP/CsPbBr₃ composite powder, a commercial red phosphor of (Sr,Ca)AlSiN₃:Eu²⁺ and a blue-emitting InGaN chip. Fig. 7a presents the EL spectrum of the assembled white LED at a driving current of 20 mA (inset is a photograph of the LED emitting bright white light). The emission wavelengths of the (Sr,Ca)AlSiN₃:Eu²⁺, α -ZrP/CsPbBr₃ composite and blue chip are 624, 521 and 456 nm, respectively. The coordinate value of the white LED is (0.395, 0.390) (CIE chromaticity diagram is given in Fig. 7b) with a luminous efficacy of 41 lm/W, a relatively low CCT of 3725 K and a CRI of 68. Compared with other white LEDs in Table 1, we can see that our reported luminous efficiency is at the middle level. The luminous efficiency value is promising to be further improved by various approaches, such as optimizing encapsulation process, changing phosphor ratio, reducing light scattering and increasing chip efficiency, etc., which needs more research in our future work. As displayed in Fig. S13,

the EL intensity of our assembled white LED only shows a small degradation after continuous lighting for 540 min. This also suggests that the synthesized α -ZrP/CsPbBr₃ composite powder has good stability. Furthermore, to evaluate the potential application of the α -ZrP/CsPbBr₃ composite for backlight display, a white LED based on the α -ZrP/CsPbBr₃ composite, a blue InGaN chip and a red KSF phosphor (with narrow emission peak, thus is suitable for displays; Fig. S14) was assembled, and its EL spectrum is shown in Fig. 7c. The CIE color coordinate of the white LED (i.e., color gamut) covers 125% of the National Television System Committee (NTSC) standard (Fig. 7d), which is superior to that of previously reported white LEDs with phosphors, PQDs and Cd-based quantum dots, as summarized in Table S1. These results prove that the α -ZrP/CsPbBr₃ composite has potential applications in lighting and displays.

4. Conclusions

An ion exchange/surface adsorption strategy was developed to realize the room-temperature synthesis and stabilization of CsPbBr₃ PQDs on α -ZrP nanosheets. The high Pb²⁺ adsorptivity and good Cs⁺ ion exchange capability of α -ZrP nanosheets promoted the heterogeneous nucleation-growth and effective anchoring of CsPbBr₃ PQDs on the surface of the α -ZrP nanosheets. As a result, the synthesized α -ZrP/CsPbBr₃ PQDs composite displayed good green-emitting performance with long-term humidity stability and excellent thermal stability. Assembled white LEDs based on the α -ZrP/CsPbBr₃ composite exhibited a low CCT and high luminous efficacy. Besides, the color gamut

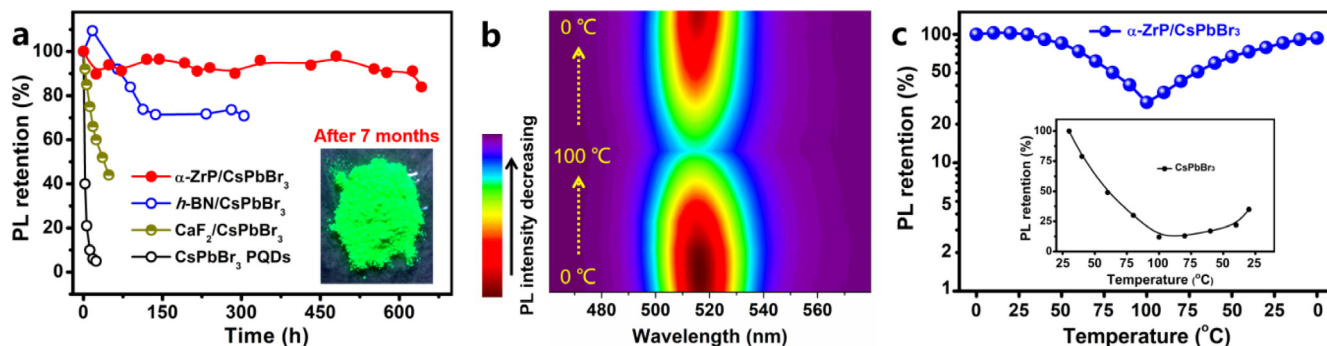


Fig. 6. (a) Humidity stability of the α -ZrP/CsPbBr₃ composite (inset: photograph under a UV light of the α -ZrP/CsPbBr₃ composite after 7 months since synthesis). Thermal stability of the α -ZrP/CsPbBr₃ composite: (b) PL intensity contour map and (c) summarized PL retention with the change of temperature. For comparison, humidity stability of CsPbBr₃ PQDs (ref. 20), CaF₂/CsPbBr₃ (ref. 20) and *h*-BN/CsPbBr₃ (ref. 22) and thermal stability of CsPbBr₃ PQDs (ref. 48) are listed in (a) and (c).

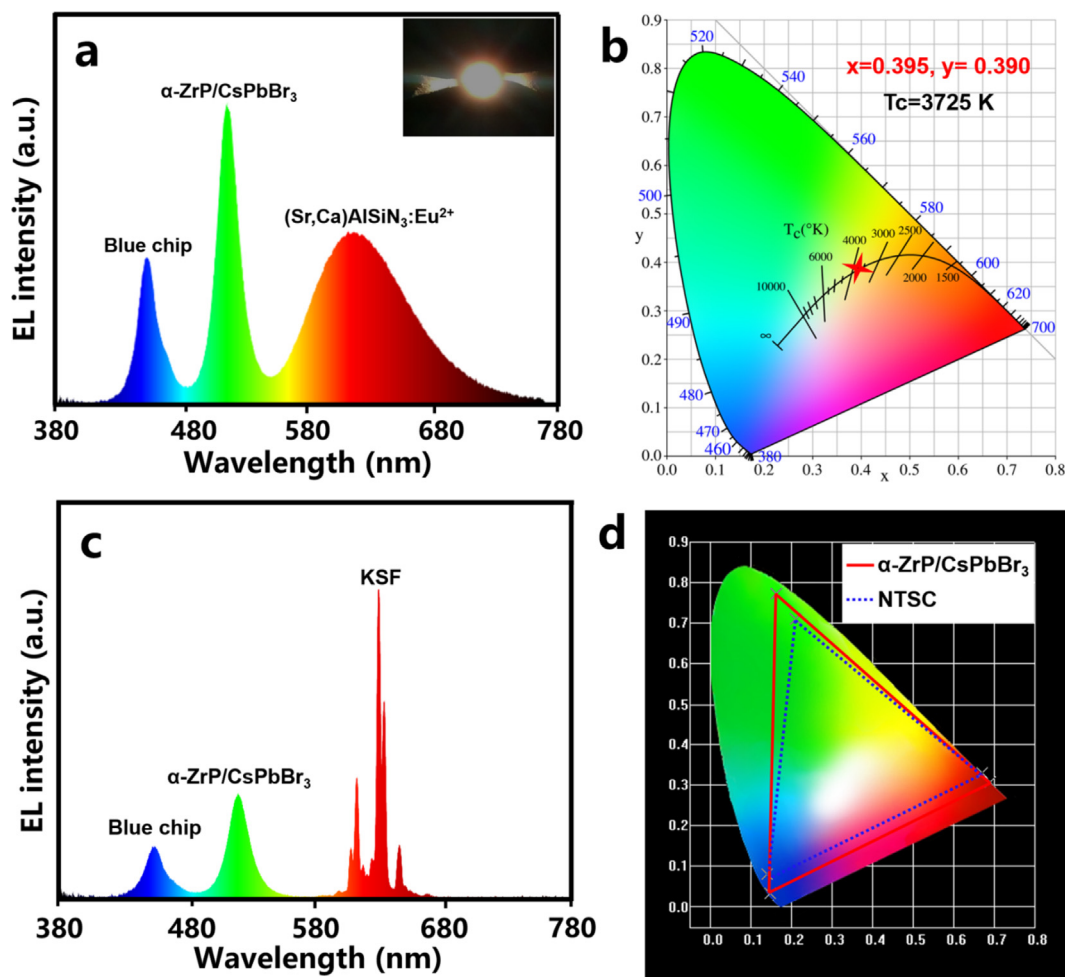


Fig. 7. (a) EL spectrum (inset: photograph of the lighting LED) and (b) CIE chromaticity diagram of the white LED constructed by the α -ZrP/CsPbBr₃ composite, (Sr,Ca)AlSiN₃:Eu²⁺ and a blue-emitting InGaN chip. (c) EL spectrum and (d) color gamut of the white LED constructed by the α -ZrP/CsPbBr₃ composite, a red KSF phosphor and a blue InGaN chip. (For interpretation of the references to color in this figure legend, the reader is referred to the web version of this article.)

of the white LEDs based on a blue InGaN chip, the green-emitting α -ZrP/CsPbBr₃ composite and a red-emitting KSF phosphor was 125% of the NTSC standard. Overall, the synthesis and stabilization of the CsPbBr₃ PQDs on the α -ZrP nanosheets were realized based on the inherent characteristics of the α -ZrP, avoiding additional surface modification process. We would like to mention that many other inorganic materials that own ion exchange/adsorption properties with Cs⁺/Pb²⁺ or a layered structure, such as Sn(HPO₄)₂·H₂O, Ti(HPO₄)₂·H₂O, mesoporous titanium phosphates and so on [27,63–65], can be used to stabilize PQDs in theory. But to achieve good photoluminescence performance, optical property and chemical stability of these inorganic

nanomaterials need to be considered [49,62]. For instance, the inorganic nanomaterials should have a large bandgap and not absorb the light emitted by PQDs. Above all, this work opens up a new way to use inorganic nanomaterials to stabilize all-inorganic PQDs and can promote the scalable synthesis of long-term stable PQDs for optoelectronic devices.

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Table 1

Comparison of the optical performance of various white LEDs.

Blue part	Green part	Red part	CCT (K)	CRI	Luminous efficacy (lm/W)	Refs.
Blue LED chip	α -ZrP/CsPbBr ₃	(Sr,Ca)AlSiN ₃ :Eu ²⁺	3725	68	41	This work
Blue LED chip	CsPbBr ₃ /EVA	(Sr,Ca)AlSiN ₃ :Eu ²⁺	2347	75	38	[14]
Blue LED chip	CsPb _{1-x} Sn _x Br ₃	CaAlSiN ₃ :Eu ²⁺	3128	74	29	[57]
Blue LED chip	CsPbBr ₃ /Cs ₂ GeF ₆ :Mn ⁴⁺		–	81	27	[36]
Blue LED chip	CsPbBr ₃	K ₂ SiF ₆ :Mn ⁴⁺	4754	85	46	[58]
Blue LED chip	CsPbBr ₃ -SiO ₂	Sr ₂ Si ₅ N ₈ :Eu ²⁺	5318	72	48	[59]
Blue LED chip	CsPbBr ₃ -SiO ₂	K ₂ SiF ₆ :Mn ⁴⁺	7425	83	64	[60]
Blue LED chip	CaF ₂ -CsPbBr ₃	K ₂ SiF ₆ :Mn ⁴⁺	–	63	–	[20]
Blue LED chip	CsPbBr ₃ /glass	CaAlSiN ₃ :Eu ²⁺	3674	83	51	[46]
Blue LED chip	CsPbBr ₃ : Na ⁺	K ₂ SiF ₆ :Mn ⁴⁺	6652	75	67	[61]
UV-chip	CsPbBr ₃	CsPbMnCl ₃ @SiO ₂	3950	82	78	[62]

Appendix A. Supplementary data

Supplementary data to this article can be found online at <https://doi.org/10.1016/j.cej.2019.122735>.

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